

<b>AUTHOR: (bachelet gb) Refined by: RESEARCH AREAS=( PHYSICS) Timespan=All years Results found: 68 Sum of the Times Cited: 4906 Average Citations per Item: 72.15 h-index: 25</b>	2012	2013	2014	2015	2016	Total	Average Citations per Year
	80	101	76	79	10	4906	136.28
<b>1 Title:</b> PSEUDOPOTENTIALS THAT WORK - FROM H TO PU <b>By:</b> BACHELET, GB; HAMANN, DR; SCHLUTER, M <b>Source:</b> PHYSICAL REVIEW B <b>Volume:</b> 26 <b>Issue:</b> 8 <b>Pages:</b> 4199-4228 <b>Published:</b> 1982	32	38	36	29	2	2725	77.86
<b>2 Title:</b> Correlation energy and spin polarization in the 2D electron gas <b>By:</b> Attaccalite, C; Moroni, S; Gori-Giorgi, P; et al. <b>Source:</b> PHYSICAL REVIEW LETTERS <b>Volume:</b> 88 <b>Issue:</b> 25 <b>Article Number:</b> 256601 <b>Published:</b> JUN 24 2002	11	17	6	12	4	281	18.73
<b>3 Title:</b> RELATIVISTIC AND CORE-RELAXATION EFFECTS ON THE ENERGY-BANDS OF GALLIUM-ARSENIDE AND GERMANIUM <b>By:</b> BACHELET, GB; CHRISTENSEN, NE <b>Source:</b> PHYSICAL REVIEW B <b>Volume:</b> 31 <b>Issue:</b> 2 <b>Pages:</b> 879-887 <b>Published:</b> 1985	7	3	9	4	0	276	8.62
<b>4 Title:</b> RELATIVISTIC NORM-CONSERVING PSEUDOPOTENTIALS <b>By:</b> BACHELET, GB; SCHLUTER, M <b>Source:</b> PHYSICAL REVIEW B <b>Volume:</b> 25 <b>Issue:</b> 4 <b>Pages:</b> 2103-2108 <b>Published:</b> 1982	3	5	4	8	0	191	5.46
<b>5 Title:</b> STRUCTURAL-ENERGY CALCULATIONS BASED ON NORM-CONSERVING PSEUDOPOTENTIALS AND LOCALIZED GAUSSIAN-ORBITALS <b>By:</b> BACHELET, GB; GREENSIDE, HS; BARAFF, GA; et al. <b>Source:</b> PHYSICAL REVIEW B <b>Volume:</b> 24 <b>Issue:</b> 8 <b>Pages:</b> 4745-4752 <b>Published:</b> 1981	0	0	1	0	0	146	4.06
<b>6 Title:</b> TOTAL-ENERGY GRADIENTS AND LATTICE-DISTORTIONS AT POINT-DEFECTS IN SEMICONDUCTORS <b>By:</b> SCHEFFLER, M; VIGNERON, JP; BACHELET, GB <b>Source:</b> PHYSICAL REVIEW B <b>Volume:</b> 31 <b>Issue:</b> 10 <b>Pages:</b> 6541-6551 <b>Published:</b> 1985	1	0	1	1	0	112	3.50
<b>7 Title:</b> DEFECTS IN DIAMOND - THE UNRELAXED VACANCY AND SUBSTITUTIONAL NITROGEN <b>By:</b> BACHELET, GB; BARAFF, GA; SCHLUTER, M <b>Source:</b> PHYSICAL REVIEW B <b>Volume:</b> 24 <b>Issue:</b> 8 <b>Pages:</b> 4736-4744 <b>Published:</b> 1981	0	1	2	0	0	104	2.89
<b>8 Title:</b> Analytic static structure factors and pair-correlation functions for the unpolarized homogeneous electron gas <b>By:</b> Gori-Giorgi, P; Sacchetti, F; Bachelet, GB <b>Source:</b> PHYSICAL REVIEW B <b>Volume:</b> 61 <b>Issue:</b> 11 <b>Pages:</b> 7353-7363 <b>Published:</b> MAR 15 2000	5	8	1	4	0	80	4.71
<b>9 Title:</b> SELF-CONSISTENT CALCULATIONS OF THE ELECTRONIC-STRUCTURE FOR IDEAL GA AND AS VACANCIES IN GAAS <b>By:</b> BACHELET, GB; BARAFF, GA; SCHLUTER, M <b>Source:</b> PHYSICAL REVIEW B <b>Volume:</b> 24 <b>Issue:</b> 2 <b>Pages:</b> 915-925 <b>Published:</b> 1981	1	0	0	0	0	75	2.08
<b>10 Title:</b> NOVEL PSEUDO-HAMILTONIAN FOR QUANTUM MONTE-CARLO SIMULATIONS <b>By:</b> BACHELET, GB; CEPERLEY, DM; CHIOCCHETTI, MGB <b>Source:</b> PHYSICAL REVIEW LETTERS <b>Volume:</b> 62 <b>Issue:</b> 18 <b>Pages:</b> 2088-2091 <b>Published:</b> MAY 1 1989	1	0	0	0	0	73	2.61
<b>11 Title:</b> ASGA ANTISITE DEFECT IN GAAS <b>By:</b> BACHELET, GB; SCHLUTER, M; BARAFF, GA <b>Source:</b> PHYSICAL REVIEW B <b>Volume:</b> 27 <b>Issue:</b> 4 <b>Pages:</b> 2545-2547 <b>Published:</b> 1983	0	0	0	0	0	70	2.06
<b>12 Title:</b> STRUCTURAL DETERMINATION OF CL-CHEMISORPTION ON SI[111] AND GE[111] BY TOTAL-ENERGY MINIMIZATION <b>By:</b> BACHELET, GB; SCHLUTER, M <b>Source:</b> PHYSICAL REVIEW B <b>Volume:</b> 28 <b>Issue:</b> 4 <b>Pages:</b> 2302-2304 <b>Published:</b> 1983	1	0	0	1	0	51	1.50

13	<b>Title:</b> Electrons and phonons in the ternary alloy CaAl <sub>2</sub> -xSix as a function of composition <b>By:</b> Giantomassi, M; Boeri, L; Bachelet, GB <b>Source:</b> PHYSICAL REVIEW B <b>Volume:</b> 72 <b>Issue:</b> 22 <b>Article Number:</b> 224512 <b>Published:</b> DEC 2005	4	0	2	3	0	48	4.00
14	<b>Title:</b> Local-spin-density functional for multideterminant density functional theory <b>By:</b> Paziani, S; Moroni, S; Gori-Giorgi, P; et al. <b>Source:</b> PHYSICAL REVIEW B <b>Volume:</b> 73 <b>Issue:</b> 15 <b>Article Number:</b> 155111 <b>Published:</b> APR 2006	1	8	4	4	0	43	3.91
15	<b>Title:</b> PSEUDOJELLIUM MODEL WITH AN APPLICATION TO LITHIUM CLUSTERS <b>By:</b> SERRA, L; BACHELET, GB; GIAI, NV; et al. <b>Source:</b> PHYSICAL REVIEW B <b>Volume:</b> 48 <b>Issue:</b> 19 <b>Pages:</b> 14708-14711 <b>Published:</b> NOV 15 1993	0	0	0	0	0	43	1.79
16	<b>Title:</b> Small Fermi energy and phonon anharmonicity in MgB <sub>2</sub> and related compounds <b>By:</b> Boeri, L; Bachelet, GB; Cappelluti, E; et al. <b>Source:</b> PHYSICAL REVIEW B <b>Volume:</b> 65 <b>Issue:</b> 21 <b>Article Number:</b> 214501 <b>Published:</b> JUN 1 2002	0	0	1	1	0	42	2.80
17	<b>Title:</b> TRACTABLE APPROACH FOR CALCULATING LATTICE-DISTORTIONS AROUND SIMPLE DEFECTS IN SEMICONDUCTORS - APPLICATION TO THE SINGLE DONOR GE IN GAP <b>By:</b> SCHEFFLER, M; VIGNERON, JP; BACHELET, GB <b>Source:</b> PHYSICAL REVIEW LETTERS <b>Volume:</b> 49 <b>Issue:</b> 24 <b>Pages:</b> 1765-1768 <b>Published:</b> 1982	0	0	0	0	0	42	1.20
18	<b>Title:</b> Pair-distribution functions of the two-dimensional electron gas <b>By:</b> Gori-Giorgi, P; Moroni, S; Bachelet, GB <b>Source:</b> PHYSICAL REVIEW B <b>Volume:</b> 70 <b>Issue:</b> 11 <b>Article Number:</b> 115102 <b>Published:</b> SEP 2004	2	4	1	1	0	40	3.08
19	<b>Title:</b> Electron-phonon interaction in graphite intercalation compounds <b>By:</b> Boeri, Lilia; Bachelet, Giovanni B.; Giantomassi, Matteo; et al. <b>Source:</b> PHYSICAL REVIEW B <b>Volume:</b> 76 <b>Issue:</b> 6 <b>Article Number:</b> 064510 <b>Published:</b> AUG 2007	2	3	4	3	1	37	3.70
20	<b>Title:</b> NONLOCAL EXCHANGE AND CORRELATION AND SEMICONDUCTOR BAND-STRUCTURE <b>By:</b> MANGHI, F; RIEGLER, G; BERTONI, CM; et al. <b>Source:</b> PHYSICAL REVIEW B <b>Volume:</b> 28 <b>Issue:</b> 10 <b>Pages:</b> 6157-6160 <b>Published:</b> 1983	0	3	0	0	1	36	1.06
21	<b>Title:</b> BAND-STRUCTURE CALCULATION FOR GAAS AND SI BEYOND THE LOCAL-DENSITY APPROXIMATION <b>By:</b> MANGHI, F; RIEGLER, G; BERTONI, CM; et al. <b>Source:</b> PHYSICAL REVIEW B <b>Volume:</b> 31 <b>Issue:</b> 6 <b>Pages:</b> 3680-3688 <b>Published:</b> 1985	0	0	0	0	1	34	1.06
22	<b>Title:</b> Unresolved problems in superconductivity of CaC(6) <b>By:</b> Mazin, I. I.; Boeri, L.; Dolgov, O. V.; et al. <b>Conference:</b> 8th International Conference on Materials and Mechanisms of Superconductivity and High Temperature Superconductors <b>Location:</b> Dresden, GERMANY <b>Date:</b> JUL 09-14, 2006 <b>Source:</b> PHYSICA C-SUPERCONDUCTIVITY AND ITS APPLICATIONS <b>Volume:</b> 460 <b>Pages:</b> 116-120 <b>Part:</b> 1 <b>Published:</b> SEP 1 2007	3	2	2	3	0	33	3.30
23	<b>Title:</b> SURFACE AND SIZE EFFECTS ON THE ELECTRONIC STATES OF SMALL METALLIC CLUSTERS - A MODEL CALCULATION <b>By:</b> BACHELET, GB; BASSANI, F; BOURG, M; et al. <b>Source:</b> JOURNAL OF PHYSICS C-SOLID STATE PHYSICS <b>Volume:</b> 16 <b>Issue:</b> 21 <b>Pages:</b> 4305-4320 <b>Published:</b> 1983	1	0	0	0	0	30	0.88
24	<b>Title:</b> CONDUCTION-BAND ENERGY OF EXCESS ELECTRONS IN LIQUID ARGON <b>By:</b> PLENKIEWICZ, B; JAYGERIN, JP; PLENKIEWICZ, P; et al. <b>Source:</b> EUROPHYSICS LETTERS <b>Volume:</b> 1 <b>Issue:</b> 9 <b>Pages:</b> 455-460 <b>Published:</b> MAY 1 1986	1	1	0	0	0	28	0.90
25	<b>Title:</b> Correlation energy and spin polarization in the 2D electron gas (vol 88, art no 256601, 2002) <b>By:</b> Attaccalite, C; Moroni, S; Gori-Giorgi, P; et al. <b>Source:</b> PHYSICAL REVIEW LETTERS <b>Volume:</b> 91 <b>Issue:</b> 10 <b>Article Number:</b> 109902 <b>Published:</b> SEP 5 2003	0	2	0	0	0	26	1.86

26	<b>Title:</b> Phase separation in the two-dimensional Hubbard model: A fixed-node quantum Monte Carlo study <b>By:</b> Cosentini, AC; Capone, M; Guidoni, L; et al. <b>Source:</b> PHYSICAL REVIEW B <b>Volume:</b> 58 <b>Issue:</b> 22 <b>Pages:</b> 14685-14688 <b>Published:</b> DEC 1 1998	1	0	0	0	1	25	1.32
27	<b>Title:</b> ROLE OF FORMS OF EXCHANGE AND CORRELATION USED IN GENERATING PSEUDOPOTENTIALS <b>By:</b> SHIRLEY, EL; MARTIN, RM; BACHELET, GB; et al. <b>Source:</b> PHYSICAL REVIEW B <b>Volume:</b> 42 <b>Issue:</b> 8 <b>Pages:</b> 5057-5066 <b>Published:</b> SEP 15 1990	0	0	1	0	0	24	0.89
28	<b>Title:</b> LONG-RANGE ORDER IN AL <sub>0.5</sub> GA <sub>0.5</sub> AS - LOCAL DENSITY CALCULATION OF THE ELECTRONIC-STRUCTURE <b>By:</b> CHRISTENSEN, NE; MOLINARI, E; BACHELET, GB <b>Source:</b> SOLID STATE COMMUNICATIONS <b>Volume:</b> 56 <b>Issue:</b> 1 <b>Pages:</b> 125-126 <b>Published:</b> 1985	0	0	0	0	0	23	0.72
29	<b>Title:</b> Local density functional for the short-range part of the electron-electron interaction <b>By:</b> Zecca, L; Gori-Giorgi, P; Moroni, S; et al. <b>Source:</b> PHYSICAL REVIEW B <b>Volume:</b> 70 <b>Issue:</b> 20 <b>Article Number:</b> 205127 <b>Published:</b> NOV 2004	3	3	1	1	0	22	1.69
30	<b>Title:</b> Variational quantum Monte Carlo calculation of the cohesive properties of cubic boron nitride <b>By:</b> Malatesta, A; Fahy, S; Bachelet, GB <b>Source:</b> PHYSICAL REVIEW B <b>Volume:</b> 56 <b>Issue:</b> 19 <b>Pages:</b> 12201-12210 <b>Published:</b> NOV 15 1997	0	0	0	0	0	22	1.10
31	<b>Title:</b> SIMULATION OF HIGH-FIELD TRANSPORT IN GAAS USING A MONTE-CARLO METHOD AND PSEUDOPOTENTIAL BAND STRUCTURES - BAND-STRUCTURE DEPENDENT TRANSPORT AND IMPACT IONIZATION IN GAAS - COMMENT <b>By:</b> CAPASSO, F; PEARSALL, TP; THORNER, KK; et al. <b>Source:</b> JOURNAL OF APPLIED PHYSICS <b>Volume:</b> 53 <b>Issue:</b> 4 <b>Pages:</b> 3324-3326 <b>Published:</b> 1982	0	0	0	0	0	18	0.51
32	<b>Title:</b> Analytic static structure factors and pair-correlation functions for the unpolarized homogeneous electron gas (vol 61, pg 7353, 2000) <b>By:</b> Gori-Giorgi, P; Sacchetti, F; Bachelet, GB <b>Source:</b> PHYSICAL REVIEW B <b>Volume:</b> 66 <b>Issue:</b> 15 <b>Article Number:</b> 159901 <b>Published:</b> OCT 15 2002	0	1	0	1	0	13	0.87
33	<b>Title:</b> CHEMICAL HARDNESS, LINEAR-RESPONSE, AND PSEUDOPOTENTIAL TRANSFERABILITY <b>By:</b> FILIPPETTI, A; VANDERBILT, D; ZHONG, W; et al. <b>Source:</b> PHYSICAL REVIEW B <b>Volume:</b> 52 <b>Issue:</b> 16 <b>Pages:</b> 11793-11804 <b>Published:</b> OCT 15 1995	0	0	0	0	0	13	0.59
34	<b>Title:</b> Chemical bonding and lattice relaxations of deep-level defects <b>By:</b> Scheffler, M.; Beeler, F.; Jepsen, O.; et al. <b>Edited by:</b> Kimerling, L.C.; Parsey, J.M., Jr. <b>Conference:</b> Thirteenth International Conference on Defects in Semiconductors <b>Location:</b> Coronado, CA, USA <b>Date:</b> 12-17 Aug. 1984 <b>Sponsor(s):</b> TMS-AIME; Def. Adv. Res. Projects Agency; NASA; Office of Naval Res; et al <b>Source:</b> Thirteenth International Conference on Defects in Semiconductors <b>Pages:</b> 45-58 <b>Published:</b> 1985	0	0	0	0	0	10	0.31
35	<b>Title:</b> PSEUDOPOTENTIALS AND PHYSICAL IONS <b>By:</b> FOCHER, P; LASTRI, A; COVI, M; et al. <b>Source:</b> PHYSICAL REVIEW B <b>Volume:</b> 44 <b>Issue:</b> 16 <b>Pages:</b> 8486-8495 <b>Published:</b> OCT 15 1991	0	0	0	2	0	9	0.35
36	<b>Title:</b> Two-dimensional electron gas: Correlation energy versus density and spin polarization <b>By:</b> Gori-Giorgi, P; Attaccalite, C; Moroni, S; et al. <b>Conference:</b> 9th International Conference on Application of the Density Functional Theory to Chemistry and Physics <b>Location:</b> MADRID, SPAIN <b>Date:</b> SEP 10-14, 2001 <b>Source:</b> INTERNATIONAL JOURNAL OF QUANTUM CHEMISTRY <b>Volume:</b> 91 <b>Issue:</b> 2 <b>Pages:</b> 126-130 <b>Published:</b> JAN 15 2003	0	0	0	1	0	8	0.57
37	<b>Title:</b> BONDING GEOMETRIES OF CL ON SI(111) AND GE(111) <b>By:</b> BACHELET, GB; SCHLUTER, M <b>Source:</b> JOURNAL OF VACUUM SCIENCE & TECHNOLOGY B <b>Volume:</b> 1 <b>Issue:</b> 3 <b>Pages:</b> 726-728 <b>Published:</b> 1983	0	0	0	0	0	8	0.24

38	<b>Title:</b> ELECTRON CORE-HOLE INTERACTIONS AT SURFACES - AN EXACTLY SOLUBLE MODEL <b>By:</b> ALTARELLI, M; BACHELET, GB; BOUCHE, V; et al. <b>Source:</b> SURFACE SCIENCE <b>Volume:</b> 129 <b>Issue:</b> 2-3 <b>Pages:</b> 447-481 <b>Published:</b> 1983	0	0	0	0	0	7	0.21
39	<b>Title:</b> Correlation energy, pair-distribution functions and static structure factors of jellium <b>By:</b> Gori-Giorgi, P; Sacchetti, F; Bachelet, GB <b>Conference:</b> International Conference on Statistical Mechanics and Strongly Correlated Systems <b>Location:</b> UNIV LA SAPIENZA, DEPT PHYS, ROME, ITALY <b>Date:</b> SEP 27-29, 1999 <b>Sponsor(s):</b> Inst Nazl Fis Nucl; Inst Nazl Fis Mat; Gruppo Nazl Stutura Mat; Univ La Sapienza, Dipartimento Fis <b>Source:</b> PHYSICA A <b>Volume:</b> 280 <b>Issue:</b> 1-2 <b>Pages:</b> 199-205 <b>Published:</b> MAY 15 2000	0	1	0	0	0	6	0.35
40	<b>Title:</b> Alkali-metal plasmons, pseudopotentials, and optical sum rules <b>By:</b> Alippi, P; LaRocca, P; Bachelet, GB <b>Source:</b> PHYSICAL REVIEW B <b>Volume:</b> 55 <b>Issue:</b> 20 <b>Pages:</b> 13835-13841 <b>Published:</b> MAY 15 1997	0	0	0	0	0	5	0.25
41	<b>Title:</b> LATTICE-DEFECTS IN SEMICONDUCTORS - TOWARDS A FINITE-TEMPERATURE THEORY <b>By:</b> BACHELET, GB; DELORENZI, G <b>Source:</b> PHYSICA SCRIPTA <b>Volume:</b> T19A <b>Pages:</b> 311-319 <b>Published:</b> 1987	0	0	0	0	0	5	0.17
42	<b>Title:</b> CORRECTION <b>By:</b> BACHELET, GB <b>Source:</b> PHYSICAL REVIEW B <b>Volume:</b> 29 <b>Issue:</b> 4 <b>Pages:</b> 2309-2309 <b>Published:</b> 1984	0	0	0	0	0	5	0.15
43	<b>Title:</b> The origin of phonon anharmonicity in MgB2 and related compounds <b>By:</b> Boeri, L; Bachelet, GB; Cappelluti, E; et al. <b>Conference:</b> International Workshop on Superconductivity in Magnesium Diboride and Related Materials <b>Location:</b> GENOA, ITALY <b>Date:</b> JUN 17-19, 2002 <b>Source:</b> SUPERCONDUCTOR SCIENCE & TECHNOLOGY <b>Volume:</b> 16 <b>Issue:</b> 2 <b>Pages:</b> 143-146 <b>Article Number:</b> PII S0953-2048(03)54516-X <b>Published:</b> FEB 2003	0	0	0	0	0	2	0.14
44	<b>Title:</b> LOCAL NORM-CONSERVING PSEUDO-HAMILTONIANS <b>By:</b> BOSIN, A; FIORENTINI, V; LASTRI, A; et al. <b>Source:</b> PHYSICAL REVIEW A <b>Volume:</b> 52 <b>Issue:</b> 1 <b>Pages:</b> 236-257 <b>Published:</b> JUL 1995	0	0	0	0	0	2	0.09
45	<b>Title:</b> Free energy of formation of lattice vacancies in silicon <b>By:</b> Bachelet, G.B.; Jacucci, G.; Car, R.; et al. <b>Edited by:</b> Engstrom, O. <b>Conference:</b> 18th International Conference on the Physics of Semiconductors <b>Location:</b> Stockholm, Sweden <b>Date:</b> 11-15 Aug. 1986 <b>Source:</b> 18th International Conference on the Physics of Semiconductors <b>Pages:</b> 801-4 vol.2 <b>Published:</b> 1987	0	0	0	0	0	2	0.07
46	<b>Title:</b> STATIC ATOMIC POLARIZABILITIES FROM NORM-CONSERVING PSEUDOPOTENTIALS <b>By:</b> BACHELET, GB; TANNER, C; SCHLUTER, M <b>Source:</b> PHYSICA STATUS SOLIDI B-BASIC RESEARCH <b>Volume:</b> 110 <b>Issue:</b> 1 <b>Pages:</b> 313-322 <b>Published:</b> 1982	0	0	0	0	0	2	0.06
47	<b>Title:</b> Small Fermi energy effects in MgB2 and related compounds <b>By:</b> Cappelluti, E; Bachelet, GB; Boeri, L; et al. <b>Conference:</b> 7th International Conference on Materials and Mechanisms of Superconductive and High Temperature Superconductors <b>Location:</b> Rio de Janeiro, BRAZIL <b>Date:</b> MAY 25-30, 2003 <b>Source:</b> PHYSICA C-SUPERCONDUCTIVITY AND ITS APPLICATIONS <b>Volume:</b> 408 <b>Pages:</b> 332-333 <b>Published:</b> AUG 2004	0	1	0	0	0	1	0.08

48	<p><b>Title:</b> Phase separation in the 2D Hubbard model: A challenging application of fixed-node QMC  <b>By:</b> Bachelet, GB; Cosentini, AC  <b>Edited by:</b> Nightingale, MP; Umrigar, CJ  <b>Conference:</b> NATO Advanced Study Institute on Quantum Monte Carlo Methods in Physics and Chemistry <b>Location:</b> CORNELL UNIV, ITHACA, NY <b>Date:</b> JUL 12-24, 1998 <b>Sponsor(s):</b> NATO Adv Study Inst; Natl Sci Fdn; Ctr Europeen Calcul Atom Molec; Cornell Univ  <b>Source:</b> QUANTUM MONTE CARLO METHODS IN PHYSICS AND CHEMISTRY <b>Book Series:</b> NATO ADVANCED SCIENCE INSTITUTES SERIES, SERIES C, MATHEMATICAL AND PHYSICAL SCIENCES <b>Volume:</b> 525 <b>Pages:</b> 375-397 <b>Published:</b> 1999</p>	0	0	0	0	0	1	0.06
49	<p><b>Title:</b> PSEUDOHAMILTONIANS AND QUANTUM MONTE-CARLO  <b>By:</b> BOSIN, A; FIORENTINI, V; LASTRI, A; et al.  <b>Edited by:</b> Broughton, J; Bristowe, P; Newsam, J  <b>Conference:</b> SYMP ON MATERIALS THEORY AND MODELLING, AT THE 1992 FALL MEETING OF THE MATERIALS RESEARCH SOC  <b>Location:</b> BOSTON, MA <b>Date:</b> NOV 30-DEC 03, 1992 <b>Sponsor(s):</b> MAT RES SOC; BIOSYM TECHNOL; CRAY RES; NCUBE  <b>Source:</b> MATERIALS THEORY AND MODELLING <b>Book Series:</b> MATERIALS RESEARCH SOCIETY SYMPOSIUM PROCEEDINGS <b>Volume:</b> 291 <b>Pages:</b> 21-26 <b>Published:</b> 1993</p>	0	0	0	0	0	1	0.04
50	<p><b>Title:</b> PSEUDOPOTENTIAL PORTABILITY IN THE QMC FRAMEWORK  <b>By:</b> MENCHI, M; BOSIN, A; MELONI, F; et al.  <b>Edited by:</b> Broughton, J; Bristowe, P; Newsam, J  <b>Conference:</b> SYMP ON MATERIALS THEORY AND MODELLING, AT THE 1992 FALL MEETING OF THE MATERIALS RESEARCH SOC  <b>Location:</b> BOSTON, MA <b>Date:</b> NOV 30-DEC 03, 1992 <b>Sponsor(s):</b> MAT RES SOC; BIOSYM TECHNOL; CRAY RES; NCUBE  <b>Source:</b> MATERIALS THEORY AND MODELLING <b>Book Series:</b> MATERIALS RESEARCH SOCIETY SYMPOSIUM PROCEEDINGS <b>Volume:</b> 291 <b>Pages:</b> 291-296 <b>Published:</b> 1993</p>	0	0	0	0	0	1	0.04
51	<p><b>Title:</b> COMPUTER-SIMULATION IN MATERIALS SCIENCE  <b>By:</b> JACUCCI, G; MARCHESE, M; BACHELET, GB; et al.  <b>Edited by:</b> CHIAROTTI, GF; FUMI, F; TOSI, MP  <b>Conference:</b> 106TH COURSE OF THE ENRICO FERMI INTERNATIONAL SCHOOL OF PHYSICS : CURRENT TRENDS IN THE PHYSICS OF MATERIALS <b>Location:</b> LERICI, ITALY <b>Date:</b> JUN 20-JUL 08, 1988 <b>Sponsor(s):</b> INT SCH PHYS ENRICO FERMI  <b>Source:</b> CURRENT TRENDS IN THE PHYSICS OF MATERIALS <b>Book Series:</b> PROCEEDINGS OF THE INTERNATIONAL SCHOOL OF PHYSICS ENRICO FERMI <b>Volume:</b> 106 <b>Pages:</b> 121-159 <b>Published:</b> 1990</p>	0	0	0	0	0	1	0.04
52	<p><b>Title:</b> PSEUDOPOTENTIALS THAT WORK - FROM H TO PU - REPLY  <b>By:</b> BACHELET, GB; HAMANN, DR; SCHLUTER, M  <b>Source:</b> PHYSICAL REVIEW B <b>Volume:</b> 37 <b>Issue:</b> 9 <b>Pages:</b> 4798-4798 <b>Published:</b> MAR 15 1988</p>	0	0	0	0	0	1	0.03
53	<p><b>Title:</b> No large lattice relaxations around the arsenic antisite defect in GaAs  <b>By:</b> Bachelet, G.B.; Scheffler, M.  <b>Edited by:</b> Chadi, J.D.; Harrison, W.A.  <b>Conference:</b> 17th International Conference on the Physics of Semiconductors <b>Location:</b> San Francisco, CA, USA <b>Date:</b> 6-10 Aug. 1984 <b>Sponsor(s):</b> IUPAP; Int. Center Theor. Phys.; AIP; APS; American Vacuum Soc.; et al  <b>Source:</b> Proceedings of the 17th International Conference on the Physics of Semiconductors <b>Pages:</b> 755-60 <b>Published:</b> 1985</p>	0	0	0	0	0	1	0.03
54	<p><b>Title:</b> GREEN-FUNCTION APPROACH TO REALISTIC CALCULATIONS OF THE ELECTRONIC-STRUCTURE OF SEMICONDUCTOR INTERFACES  <b>By:</b> MOLINARI, E; BACHELET, GB; ALTARELLI, M  <b>Source:</b> SURFACE SCIENCE <b>Volume:</b> 152 <b>Issue:</b> APR <b>Pages:</b> 1178-1184 <b>Published:</b> 1985</p>	0	0	0	0	0	1	0.03
55	<p><b>Title:</b> SELF-CONSISTENT CALCULATIONS OF THE ELECTRONIC-STRUCTURE FOR IDEAL GA AND AS VACANCIES IN GAAS  <b>By:</b> BACHELET, GB; BARAFF, GA; SCHLUTER, M  <b>Source:</b> BULLETIN OF THE AMERICAN PHYSICAL SOCIETY <b>Volume:</b> 26 <b>Issue:</b> 3 <b>Pages:</b> 256-256 <b>Published:</b> 1981</p>	0	0	0	0	0	1	0.03



